

TN805, TN815 TS820, TYN608

Sensitive and standard 8 A SCRs

Features

- On-state rms current, I_{T(RMS)} 8 A
- Repetitive peak off-state voltage, V_{DRM}/V_{RRM} 600 and 800 V
- Triggering gate current, I_{GT} 0.2 to 15 mA

Description

Available either in sensitive (TS8) or standard (TN8 / TYN) gate triggering levels, the 8 A SCR series is suitable to fit all modes of control found in applications such as overvoltage crowbar protection, motor control circuits in power tools and kitchen aids, inrush current limiting circuits, capacitive discharge ignition and voltage regulation circuits.

Available in through-hole or surface-mount packages, they provide an optimized performance in a limited space.

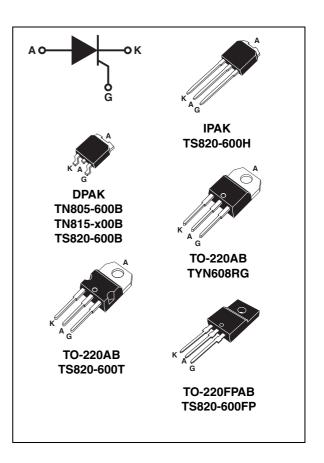


Table 1. Device summary

Order code	Voltage (x00) V _{DRM} /V _{RRM}	Sensitivity	Package	
Order code			I _{GT}	rackage	
TS820-600B	X		0.2 mA	DPAK	
TS820-600H	Х		0.2 mA	IPAK	
TS820-600T	Х		0.2 mA	TO-220AB	
TS820-600FP	Х		0.2 mA	TO-220FPAB	
TN805-600B	Х		5 mA	DPAK	
TN815-x00B	Х	Х	15 mA	DPAK	
TYN608RG	Х		15 mA	TO-220AB	

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1 Characteristics

Table 2. Absolute ratings (limiting values)

				Va	lue	
Symbol	Parameter				TYN608	Unit
I	On-state rms current (180° conduc	ction angle)	T _c = 110 °C		8	Α
I _{T(RMS)}	On-state mis current (100 conduct	citori arigie)	T0-220FPAB, $T_c = 91$ °C		O	A
	(AV) Average on-state current (180° conduction angle)		T _c = 110 °C	91 °C		Λ.
I _{T(AV)}			T0-220FPAB, T _c = 91 °C			Α
1 .	Non repetitive surge peak	$t_p = 8.3 \text{ ms}$	T _ 25 °C	73	100	Α
I _{TSM}	on-state current	$t_p = 10 \text{ ms}$	- T _j = 25 °C	70	95	
I ² t	I ² t value for fusing	$t_p = 10 \text{ ms}$	T _j = 25 °C	24.5	45	A ² S
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100 \text{ ns}$ $F = 60 \text{ Hz}$		T _j = 125 °C	5	50	A/µs
I _{GM}	Peak gate current	t _p = 20 μs	T _j = 125 °C	4		Α
P _{G(AV)}	Average gate power dissipation $T_j = 125 ^{\circ}\text{C}$			1		W
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 125		°C
V _{RGM}	Maximum peak reverse gate voltage	ge (for TN8x5 ar	nd TYN608 only)		5	V

Table 3. Sensitive electrical characteristics ($T_i = 25$ °C, unless otherwise specified)

Symbol	Test conditio	Test conditions					
I _{GT}	V 40 V D 440 O		MAX.	200	μΑ		
V _{GT}	$V_D = 12 \text{ V}, R_L = 140 \Omega$		MAX.	0.8	V		
V _{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$, $R_{GK} = 220 \Omega$	T _j = 125 °C	MIN.	0.1	V		
V _{RG}	I _{RG} = 10 μA		MIN.	8	V		
I _H	I_T = 50 mA, R_{GK} = 1 k Ω	MAX.	5	mA			
ΙL	$I_G = 1 \text{ mA}$,, $R_{GK} = 1 \text{ k}\Omega$		MAX.	6	mA		
dV/dt	$V_D = 65\% V_{DRM}, R_{GK} = 220 \Omega$ $T_j = 1$		MIN.	5	V/µs		
V _{TM}	$I_{TM} = 16 \text{ A}, t_p = 380 \ \mu\text{s}$	T _j = 25 °C	MAX.	1.6	V		
V _{t0}	Threshold voltage	T _j = 125 °C	MAX.	0.85	V		
R _d	Dynamic resistance $T_j = 125 ^{\circ}\text{C}$		MAX.	46	mΩ		
I _{DRM}	V	T _j = 25 °C	MAX.	5	μΑ		
I _{RRM}	$V_{DRM} = V_{RRM}, H_{GK} = 220.52$		IVIAA.	1	mA		

Table 4. Standard electrical characteristics ($T_j = 25$ °C, unless otherwise specified)

Symbol	Test conditions				TN815	TYN608	Unit
1			MIN.	0.5	2	2	mA
I _{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$		MAX.	5	15	15	ША
V _{GT}			MAX.		1.3		V
V_{GD}	$V_D = V_{DRM}$, $R_L = 3.3 \text{ k}\Omega$	T _j = 125 °C	MIN.		0.2		V
I _H	I _T = 100 mA , gate open		MAX.	25	40	30	mA
IL	I _G = 1.2 I _{GT}		MAX.	30	50	70	mA
dV/dt	V _D = 67% V _{DRM,} gate open	T _j =125 °C	MIN.	50	150	150	V/µs
V _{TM}	$I_{TM} = 16 \text{ A}$ $t_p = 380 \mu \text{s}$ $T_j = 25 ^{\circ}\text{C}$		MAX.	1.6			V
V _{t0}	Threshold voltage	T _j = 125 °C	MAX.		0.85		V
R _d	Dynamic resistance $T_j = 125 ^{\circ}\text{C}$		MAX.	46			mΩ
I _{DRM}	V -V	T _j = 25 °C	MAX.	5			μΑ
I _{RRM}	$V_{DRM} = V_{RRM}$	T _j = 125 °C	IVIAA.		2		mA

Table 5. Thermal resistance

Symbol	Parameter				Unit
D	Junction to case (DC)		DPAK, IPAK, TO-220AB	1.3	°C/W
R _{th(j-c)}			TO-220FPAB	4.6	C/VV
		$S^{(1)} = 0.5 \text{ cm}^2$	DPAK	70	
R _{th(j-a)}	R _{th(j-a)} Junction to ambient (DC)		IPAK	100	°C/W
			TO-220AB, TO-220FPAB	60	

^{1.} S = Copper surface under tab

P(W)

3

2

Figure 1. Maximum average power dissipation versus average on-state current

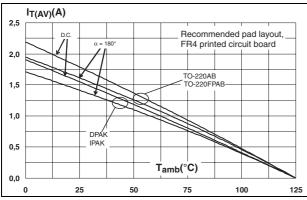
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Figure 2. Average and DC on-state current versus case temperature

360°

Figure 3. Average and DC on-state current versus ambient temperature

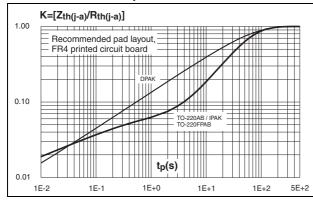
Figure 4. Relative variation of thermal impedance junction to case versus pulse duration



0.5 | Te-3 | Te-2 | Te-1 | Te-

Figure 5. Relative variation of thermal impedance junction to ambient versus pulse duration

Figure 6. Relative variation of gate trigger current and holding current versus junction temperature for TS820



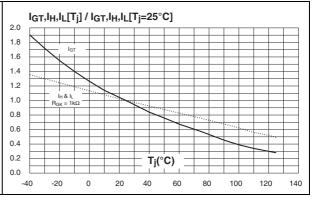
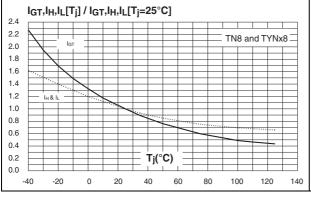
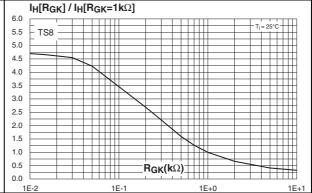


Figure 7. Relative variation of gate trigger and holding current versus junction temperature

Figure 8. Relative variation of holding current versus gate-cathode resistance (typical values)





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Figure 9. Relative variation of dV/dt immunity Figure 10. Relative variation of dV/dt immunity versus gate-cathode resistance (typical values) for TS820 (typical values) for TS820

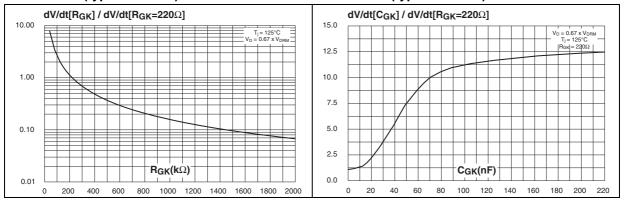


Figure 11. Surge peak on-state current versus Figure 12. Non-repetitive surge peak on-state current and corresponding values of I²t

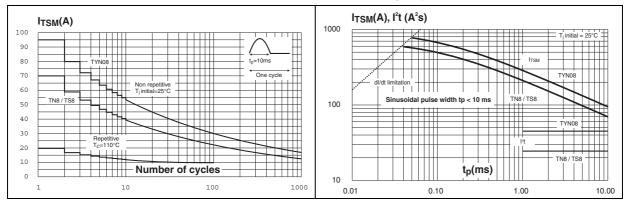
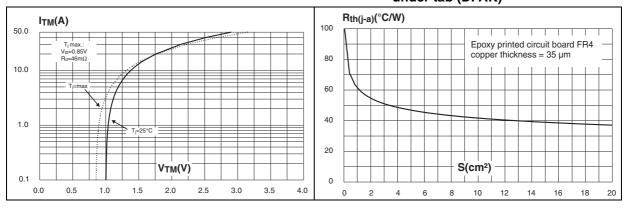


Figure 13. On-state characteristics (maximum Figure 14. Thermal resistance junction to values)

Thermal resistance junction to ambient versus copper surface under tab (DPAK)



2 Ordering information scheme

Figure 15. TN8 series

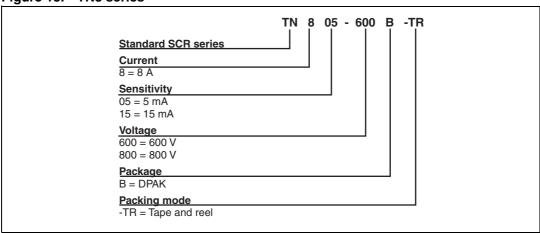


Figure 16. TS8 series

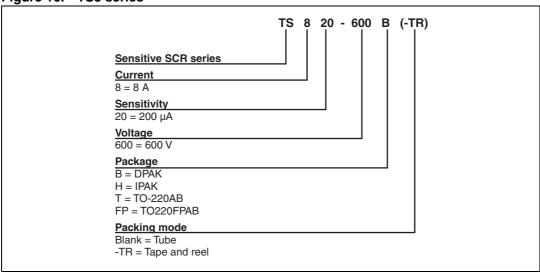
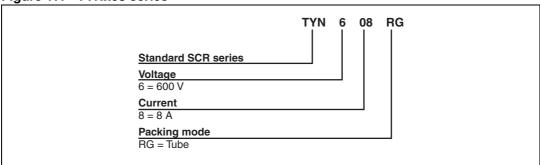


Figure 17. TYNx08 series

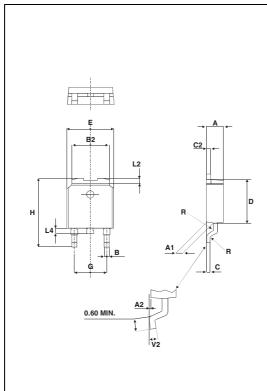


3 Package information

- Epoxy meets UL94, V0
- Lead-free packages
- Recommended torque: 0.4 to 0.6 N⋅m

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Table 6. DPAK dimensions



	Dimensions				
Ref.	Millim	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
Α	2.20	2.40	0.086	0.094	
A1	0.90	1.10	0.035	0.043	
A2	0.03	0.23	0.001	0.009	
В	0.64	0.90	0.025	0.035	
B2	5.20	5.40	0.204	0.212	
С	0.45	0.60	0.017	0.023	
C2	0.48	0.60	0.018	0.023	
D	6.00	6.20	0.236	0.244	
Е	6.40	6.60	0.251	0.259	
G	4.40	4.60	0.173	0.181	
Н	9.35	10.10	0.368	0.397	
L2	0.80 typ.		0.03	1 typ.	
L4	0.60	1.00	0.023	0.039	
V2	0°	8°	0°	8°	

Figure 18. Footprint (dimensions in mm)

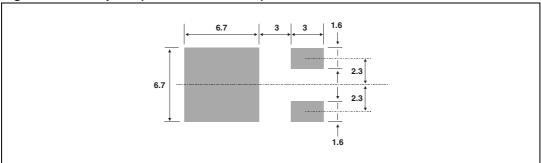
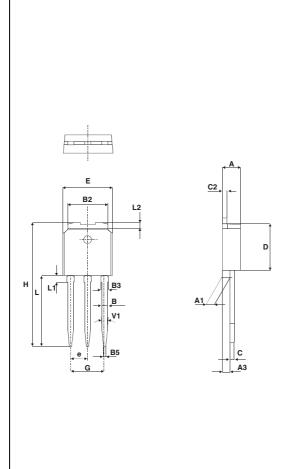


Table 7. IPAK dimensions



		Dimensions				
Ref.	Mi	Millimete		neters I		
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.20		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
А3	0.70		1.30	0.027		0.051
В	0.64		0.90	0.025		0.035
B2	5.20		5.40	0.204		0.212
В3			0.95			0.037
B5		0.30			0.035	
С	0.45		0.60	0.017		0.023
C2	0.48		0.60	0.019		0.023
D	6		6.20	0.236		0.244
Е	6.40		6.60	0.252		0.260
е		2.28			0.090	
G	4.40		4.60	0.173		0.181
Н		16.10			0.634	
L	9		9.40	0.354		0.370
L1	0.8		1.20	0.031		0.047
L2		0.80	1		0.031	0.039
V1		10°			10°	

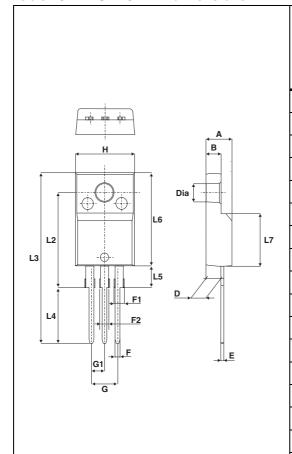
Dimensions Ref. Millimeters Inches Min. Max. Min. Max. 4.40 4.60 0.173 0.181 Α С 1.23 1.32 0.048 0.051 H2 D 2.40 2.72 0.094 0.107 Dia Ε 0.49 0.019 0.70 0.027 L5 0.61 0.024 L7 0.88 0.034 F1 1.14 1.70 0.044 0.066 L6 F2 1.14 1.70 0.044 0.066 L2 G 4.95 5.15 0.194 0.202 D L9 G1 2.40 2.70 0.094 0.106 H2 10 10.40 0.393 0.409 L4 L2 16.4 typ. 0.645 typ. L4 13 14 0.511 0.551 L5 2.65 2.95 0.104 0.116 L6 15.25 15.75 0.600 0.620 6.20 L7 0.244 0.259 6.60 L9 3.50 3.93 0.137 0.154 2.6 typ. 0.102 typ. Diam. 3.75 0.147 0.151

Table 8. TO-220AB dimensions (for TS820-xxxT)

Dimensions Ref. Millimeters Inches Min. Typ. Max. Min. Тур. Max. 15.20 15.90 0.598 0.625 Α 0.147 a1 3.75 В a2 13.00 14.00 0.511 0.551 В 10.00 10.40 0.393 0.409 b1 0.61 0.88 0.024 0.034 0.051 b2 1.23 1.32 0.048 14 С 4.40 4.60 0.173 0.181 13 с1 0.49 0.70 0.019 0.027 c2 c2 2.40 2.72 0.094 0.107 a2 2.40 0.094 0.106 2.70 е F 6.20 6.60 0.244 0.259 ØΙ 3.75 3.85 0.147 0.151 0.661 14 15.80 16.40 16.80 0.622 0.646 L 2.65 2.95 0.104 0.116 12 1.14 0.044 0.066 1.70 13 1.14 1.70 0.044 0.066 Μ 2.60 0.102

Table 9. TO-220AB dimensions (for TYNx8 series)

Table 10. TO-220FPAB dimensions



	Dimensions				
Ref.	Millim	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
Α	4.4	4.6	0.173	0.181	
В	2.5	2.7	0.098	0.106	
D	2.5	2.75	0.098	0.108	
Е	0.45	0.70	0.018	0.027	
F	0.75	1	0.030	0.039	
F1	1.15	1.70	0.045	0.067	
F2	1.15	1.70	0.045	0.067	
G	4.95	5.20	0.195	0.205	
G1	2.4	2.7	0.094	0.106	
Н	10	10.4	0.393	0.409	
L2	16	Тур.	0.63	Тур.	
L3	28.6	30.6	1.126	1.205	
L4	9.8	10.6	0.386	0.417	
L5	2.9	3.6	0.114	0.142	
L6	15.9	16.4	0.626	0.646	
L7	9.00	9.30	0.354	0.366	
Dia.	3.00	3.20	0.118	0.126	

4 Ordering information

Table 11. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
TN805-600B-TR	TN805600	DPAK	0.3 g	2500	Tape and reel
TN815-600B-TR	TN815600	DPAK	0.3 g	2500	Tape and reel
TN815-800B-TR	TN815800	DPAK	0.3 g	2500	Tape and reel
TS820-600B	TS820600	DPAK	0.3 g	75	Tube
TS820-600B-TR	TS820600	DPAK	0.3 g	2500	Tape and reel
TS820-600H	TS820600	IPAK	0.4 g	75	Tube
TS820-600T	TS820600T	TO-220AB	2.3 g	50	Tube
TS820-600FP	TS820600	TO-220FPAB	2.0 g	50	Tube
TYN608RG	TYN608	TO-220AB	2.3 g	50	Tube

5 Revision history

Table 12. Document revision history

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Date	Revision	Changes	
Apr-2002	4A	Last update.	
13-Feb-2006	5	TO-220AB delivery mode changed from bulk to tube. ECOPACK statement added.	
22-Jan-2010	6	Alpha definition updated in <i>Figure 1</i> . Thermal resistance, junction to case, updated in <i>Table 5</i> .	
10-Oct-2011	7	Added TO-220FPAB package. Removed 700 V and 1000 V products.	

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